

# isc N-Channel MOSFET Transistor

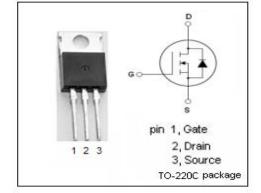
## DMG3N60SCT

#### • FEATURES

- Static drain-source on-resistance:  $\mathsf{RDs}(\mathsf{on}) \leq 3.5 \Omega$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



- DC/DC Converter
- Motor Control

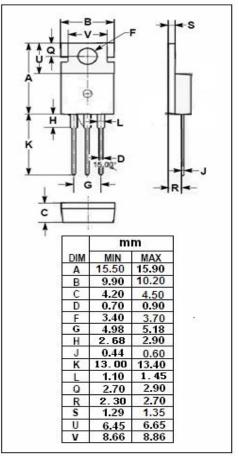


### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	V		
V <sub>GS</sub>	Gate-Source Voltage	±30	V	
I <sub>D</sub>	Drain Current-Continuous	3.3	А	
I <sub>DM</sub>	Drain Current-Single Pulsed 3.7		А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	104	W	
Tj	Max. Operating Junction Temperature	150	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature -55~150		${\mathbb C}$	

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	1.2	°C/W





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =250 μ A	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =1.5A			3.5	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V			1	μА
V <sub>SD</sub>	Diode forward voltage	I <sub>S</sub> =3A; V <sub>GS</sub> = 0V			1.5	V



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